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# Maximum Power Dissipation Rating:

1.04 watts

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## Features Provided:

Electrostatic sensitive and hermetically sealed and burn in and programmed

## Inclosure Material:

Ceramic

# Inclosure Configuration:

Flat pack

# Output Logic Form:

Transistor-transistor logic

# Case Outline Source And Designator:

F-6 mil-m-38510

# **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

7.0 volts power source

#### Time Rating Per Chacteristic:

40.00 nanoseconds delay

#### Memory Device Type:

Rom

#### **Nuclear Hardness Critical Feature:**

Hardened

#### Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### Terminal Type And Quantity:

24 flat leads

#### Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

Fiig:

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